SDAS027B - APRIL 1984 - REVISED JANUARY 1995

 3-State I/O-Type Read-Back Inputs Bus-Structured Pinout 	DW OR N PACKAGE (TOP VIEW)					
 Bus-Structured Pinout 						
 True Logic Outputs 						
Package Options Include Plastic	1D [2 19] 1Q					
Small-Outline (DW) Packages and Standard	2D 🛛 3 18 🕽 2Q					
Plastic (N) 300-mil DIPs	3D 🛛 4 17 🗍 3Q					
	4D 🛛 5 16 🕽 4Q					
description	5D 🛛 6 15 🗍 5Q					
This 8-bit latch is designed specifically for storing	6D 🛛 7 14 🕽 6Q					
the contents of the input data bus and providing	7D 🛛 8 13 🗍 7Q					
the capability of reading back the stored data onto	8D 🛛 9 12 🗍 8Q					
the input data bus.	GND [10 11] LE					

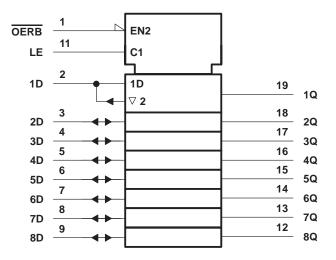
The eight latches are transparent D-type latches. While the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs.

Read back is provided through the output-enable (OERB) input. When OERB is taken low, the data present at the output of the data latches is allowed to pass back onto the input data bus. When OERB is taken high, the output of the data latches is isolated from the D inputs. OERB does not affect the internal operation of the latches; however, precautions should be taken not to create a bus conflict.

The SN74ALS990 is characterized for operation from 0°C to 70°C.

logic symbol[†]

d

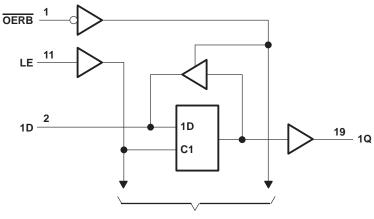


[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



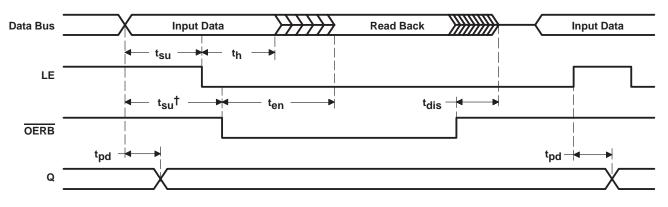
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logic diagram (positive logic)



To Seven Other Channels

timing diagram



[†] This setup time ensures that the read-back circuit will not create a conflict on the input data bus.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage, V _{CC}	
Input voltage, V _I (OERB and LE)	
Voltage applied to D inputs	5.5 V
Operating free-air temperature range, T _A	0°C to 70°C
Storage temperature range	−65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



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recommended operating conditions

			MIN	NOM	MAX	UNIT
VCC	Supply voltage		4.5	5	5.5	V
VIH	High-level input voltage		2			V
VIL	Low-level input voltage				0.8	V
lau		Q			-2.6	A
ЮН		D			-0.4	mA
1	/IH High-level input voltage /IL Low-level input voltage OH High-level output current OL Low-level output current w Pulse duration, LE high su Setup time h Hold time, data after LE↓	Q			24	mA
OL		D			8	ША
tw	Pulse duration, LE high		10			ns
1	Setup time	Data before LE \downarrow	10			
^I SU	Pulse duration, LE high Setup time	Data before OERB↓	10			ns
t _h	Hold time, data after LE \downarrow		5			ns
Тд	Operating free-air temperature		0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	RAMETER TEST CONDITIONS						
VIK		V _{CC} = 4.5 V,	lj = – 18 mA			-1.2	V	
V	All outputs	V _{CC} = 4.5 V to 5.5 V,	$I_{OH} = -0.4 \text{ mA}$	V _{CC} -2	2		V	
VOH	Q	$V_{CC} = 4.5 V,$	I _{OH} = - 2.6 mA	2.4	3.2		V	
	D		$I_{OL} = 4 \text{ mA}$		0.25	0.4		
Vei		V _{CC} = 4.5 V	IOL = 8 mA		0.35	0.5	v	
VOL			I _{OL} = 12 mA		0.25		v	
	Q	V _{CC} = 4.5 V	I _{OL} = 24 mA		0.35	0.5		
1.	OERB, LE		VI = 5.5 V			0.1	mA	
11	D inputs	V _{CC} = 5.5 V	V _I = 7 V			0.1	ШA	
	OERB, LE		<u>\</u>			20	A	
ΊΗ	D inputs [‡]	V _{CC} = 5.5 V,	V _I = 2.7 V			20	μA	
	OERB, LE		V(- 0.4.V)			-0.1		
ΊL	D inputs [‡]	V _{CC} = 5.5 V,	V _I = 0.4 V			-0.1	mA	
۱ ₀ §		V _{CC} = 5.5 V,	V _O = 2.25 V	-30		-112	mA	
		<u>V_{CC} =</u> 5.5 V,	Outputs high		27	50	mA	
ICC		OERB high	Outputs low		40	70	ША	

[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

 \ddagger For I/O ports (QA thru QH), the parameters IIH and IIL include the off-state output current.

§ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.



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switching characteristics (see Figure 1)

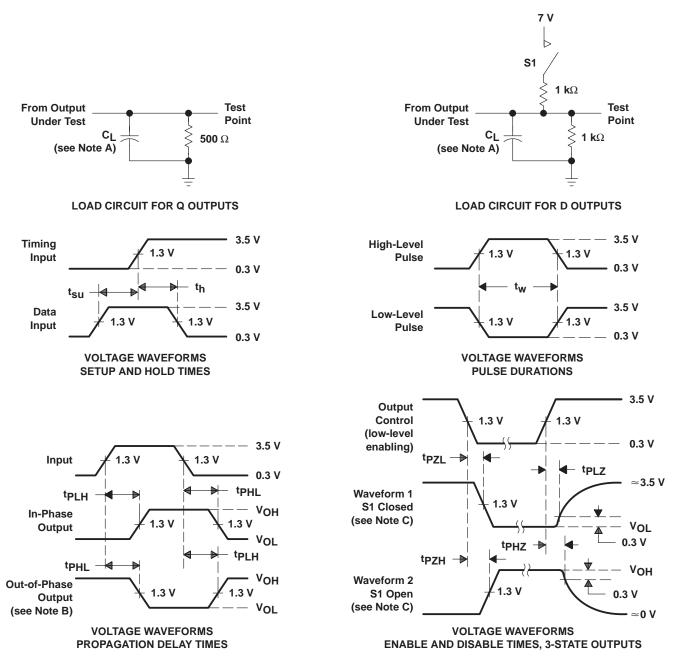
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 4.5 C _L = 50 pF T _A = MIN t	UNIT	
			MIN	MAX	
^t PLH	D		4	17	20
^t PHL	D	Q	5	24	ns
^t PLH	LE		6	26	ns
^t PHL	LL	Q	8	26	115
t _{en} ‡	OERB	D	4	21	ns
t _{dis} §	OERB	D	4	19	ns

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

 $t_{en} = t_{PZH} \text{ or } t_{PZL}$ $t_{dis} = t_{PHZ} \text{ or } t_{PLZ}$



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PARAMETER MEASUREMENT INFORMATION

NOTES: A. CL includes probe and jig capacitance.

- B. When measuring propagation delay times of 3-state outputs, switch S1 is open.
- C. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 D. All input pulses have the following characteristics: PRR ≤ 1 MHz, t_f = t_f = 2 ns, duty cycle = 50%.

Figure 1. Load Circuits and Voltage Waveforms





PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74ALS990DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	ALS990	Samples
SN74ALS990DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	ALS990	Samples
SN74ALS990DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	ALS990	Samples
SN74ALS990N	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	NIPDAU	N / A for Pkg Type	0 to 70	SN74ALS990N	Samples
SN74ALS990NE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	NIPDAU	N / A for Pkg Type	0 to 70	SN74ALS990N	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.



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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

REEL DIMENSIONS

TEXAS INSTRUMENTS





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALS990DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

14-Jul-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALS990DWR	SOIC	DW	20	2000	367.0	367.0	45.0

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



DW0020A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0020A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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